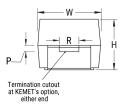


T498B685K016ATE1K8

T498, Tantalum, MnO2 Tantalum, High Temperature, 6.8 uF, 10%, 16 VDC, SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200, N/A, 1.8 Ohms, 3528, 2.1mm

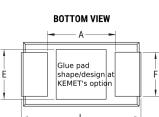
CATHODE (-) END VIEW



SIDE VIEW

ANODE (+) END VIEW





Click here for the 3D model.

Dimensions	
Footprint	3528
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
Т	0.13mm REF
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm
А	1.9mm MIN
В	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
Р	0.5mm REF
R	1mm REF
Х	0.1mm +/-0.1mm

Т

Packaging Specifications		
Packaging	T&R, 178mm	
Packaging Quantity	2000	

General Information	
Series	T498
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200
Features	Automotive, 150C
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	107.45 mg
Shelf Life	156 Weeks
MSL	1

Specifications	
Capacitance	6.8 uF
Capacitance Tolerance	10%
Voltage DC	16 VDC (85C), 12.75 VDC (125C), 10.72 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5% 120Hz 25C
Failure Rate	N/A
ESR	1800 mOhms (100kHz 25C)
Ripple Current	217 mA (rms, 100kHz 25C), 195.3 mA (rms, 85C), 65.1 mA (rms, 150C)
Leakage Current	1.1 uA (5min 25°C)

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